

FEATURES

- Offers Bandwidth Allocation of PCI Express™ Signal Using Two-Lane 1:2 Multiplexer/Demultiplexer
- Vcc Operating Range From 1.7 V to 1.9 V
- Supports Data Rates of 2.5 Gbps
- Port-Port Crosstalk (–39 dB at 1.25 GHz)
- OFF Port Isolation (–38 dB at 1.25 GHz)
- Low ON-State Resistance (10 Ω Typ)
- Low Input/Output Capacitance (3.5 pF Typ)

- Excellent Differential Skew (5 ps Max)
- Minimal Propagation Delay
- ESD Performance Tested Per JESD 22
 - 2000-V Human-Body Model (A114-B, Class II)
 - 1000-V Charged-Device Model (C101)

DESCRIPTION/ORDERING INFORMATION

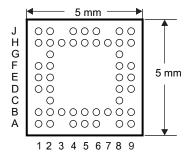
The TS2PCIE2212 can be used to muxltiplex/demultiplex two PCI Express™ lanes, each representing differential pairs of receive (RX) and transmit (TX) signals. The switch operates at the PCI Express bandwidth standard of 2.5-Gbps signal-processing speed. The device is composed of two banks, with each bank accommodating two sources (source A and source B) and two destinations (destination A and destination B).

When a logic-level low is applied to the control (CTRL) pin, source A is connected to destination A and source B is connected to destination B. When a logic-level high is applied to CTRL, source A is connected to destination B, while source B and destination A are open.

ORDERING INFORMATION

T _A	PACI	KAGE	ORDERABLE PART NUMBER	TOP-SIDE MARKING
0°C to 85°C	BGA – ZAH	Tape and reel	TS2PCIE2212ZAHR	

ZAH PACKAGE (BOTTOM VIEW)



TERMINAL ASSIGNMENTS

	1	2	3	4	5	6	7	8	9
Α	CTRL0	TxSB:0P		TxSA:0P	GND	TxDA:0P		TxDB:0P	NC
В	RxSA:0P	GND	TxSB:0N	TxSA:0N	VDD	TxDA:0N	TxDB:0N	GND	RxDA:0P
С		RxSA:0N						RxDA:0N	
D	RxSB:0P	RxSB:0N						RxDB:0N	RxDB:0P
E	GND	VDD						VDD	GND
F	TxSA:1P	TxSA:1N						TxDA:1N	TxDA:1P
G		TxSB:1N						TxDB:1N	
Н	TxSB:1P	GND	RxSA:1N	RxSB:1N	VDD	RxDB:1N	RxDA:1N	GND	TxDB:1P
J	NC	RxSA:1P		RXSB:1P	GND	RXDB:1P		RxDA:1P	CTRL1

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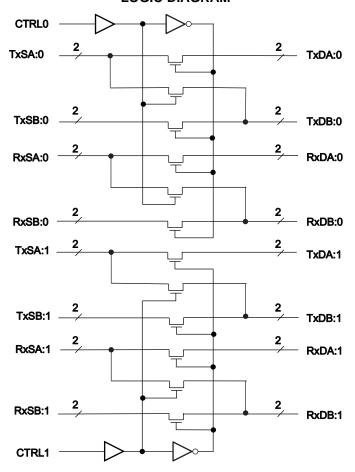
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PIN DESCRIPTION

NAME	FUNCTION
TxSA:nP, TxSA:nN	Source A transmit pair
RxSA:nP, RxSA:nN	Source A receive pair
TxSB:nP, TxSB:nN	Source B transmit pair
RxSB:nP, RxSB:nN	Source B receive pair
TxDA:nP, TxDA:nN	Destination A transmit pair
RxDA:nP, RxDA:nN	Destination A receive pair
TxDB:nP, TxDB:nN	Destination B transmit pair
RxDB:nP, RxDB:nN	Destination B receive pair
CTRL0	Control signal for bank 0
CTRL1	Control signal for bank 1
V_{DD}	Positive supply voltage
GND	Ground (0 V)
NC	No internal connection

LOGIC DIAGRAM





SCDS209-JUNE 2006

FUNCTION TABLE

CTRLn	FUNCTION
L	SA:n = DA:n, SB:n = DB:n
Н	SA:n = DB:n, DA:n = open, SBin = open

Absolute Maximum Ratings(1)

over operating free-air temperature range (unless otherwise noted)

				MIN	MAX	UNIT
V_{DD}	Supply voltage range		-0.5	2.5	V	
V _{IN}	Control input voltage range ⁽²⁾⁽³⁾			-0.5	2.5	V
V _{I/O}	Switch I/O voltage range ⁽²⁾⁽³⁾⁽⁴⁾				2.5	V
I _{IK}	Control input clamp current	$V_{IN} < 0$ and $V_{I/O} < 0$			50	mA
I _{I/OK}	I/O port clamp current	V _{IN} < 0 and V _{I/O} < 0			50	mA
I _{I/O}	ON-state switch current ⁽⁵⁾				±100	mA
	Continuous current through V _{DD} or GND				±100	mA
θ_{JA}	Package thermal impedance (6)			TBD	°C/W	
T _{stg}	Storage temperature range			-65	150	°C

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

All voltages are with respect to ground, unless otherwise specified.

Recommended Operating Conditions

			MIN	TYP	MAX	UNIT
V_{DD}	Supply voltage		1.7	1.8	1.9	V
V_{IH}	High-level control input voltage	CTRL	0.65 V _{DD}			V
V _{IL}	Low-level control input voltage	CTRL			0.35 V _{DD}	V
V _{IO}	Data input/output voltage		0		V_{DD}	V
T _A	Operating free-air temperature		0		85	°C

The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

⁽⁴⁾ V_1 and V_0 are used to denote specific conditions for $V_{1/0}$.

 ⁽⁵⁾ I_I and I_O are used to denote specific conditions for I_{I/O}.
 (6) The package thermal impedance is calculated in accordance with JESD 51-7.



Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER			TEST CONDITIONS		T _A = (0°C to 8	35°C	LINUT
P	AKAWETEK		MIN	TYP	MAX	UNIT		
V _{IK}	Control inputs	V _{DD} = 1.7 V,	$I_{IN} = -18 \text{ mA}$				-1.8	V
I _{IN}	Control inputs	V _{DD} = 1.9 V,	$V_{IN} = V_{DD}$ or GND				±1	μΑ
I _{OZ}		V _{DD} = 1.9 V,	$V_O = 0 \text{ to } 1.9 \text{ V},$ $V_I = 0,$	Switch OFF			±5	μΑ
I _{CC}		$V_{DD} = 1.9 \text{ V},$ $V_{IN} = V_{DD} \text{ or GND},$	$I_{I/O} = 0,$	Switch ON or OFF		160	300	μΑ
C _{in}	Control inputs	V _{DD} = 1.9 V,	$V_{IN} = V_{DD}$ or GND			0.5	1.0	pF
C _{IO(OFF)}	SB or DA port	$V_{I/O} = 0 V$,	Switch OFF			1.4	1.5	pF
C _{IO(ON)}		$V_{I/O} = 0 V$,	Switch ON			3.5	4	pF
_		V _{DD} = 1.7 V,	V _I = 0 V,	I _O = 10 mA		10	14	Ω
r _{on}		V _{DD} = 1.7 V,	V _I = 1.5 V,	I _O = -10 mA		12	17	2.2
$\Delta r_{on(flat)}$		V _{DD} = 1.7 V,	I _O = 10 mA,	$V_{I} = 1.5 \text{ V} \pm 0.4 \text{ V}$		2.5	5	Ω

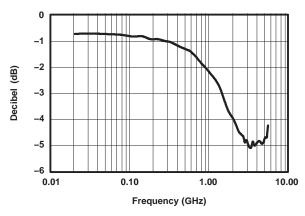
Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	DESCRIPTION	TEST CONDITIONS	T _A =	UNIT		
PARAMETER	DESCRIPTION	TEST CONDITIONS	MIN	TYP	MAX	UNII
DR	Data rate per TX or RX pair			2.5		Gbps
t _{pd}	Propagation delay, Sx to Dx	See Figure 7		250		ps
t _{sk}	Intra-pair skew	f =1.25 GHz, See Figure 7			5	ps
t _{en} (t _{PZL} , t _{PZH})	Switch turn-on delay, CTRL to DA	See Figure 6			5	ns
t _{dis} (t _{PLZ} , t _{PHZ})	Switch turn-off delay, CTRL to DA	See Figure 6			2.5	ns
I _{LOSS}	Differential insertion loss	f =1.25 GHz, R_{LOAD} = 50 Ω , See Figure 1		-2.5	-3.2	dB
R _{LOSS}	Differential return loss	f =1.25 GHz, R_{LOAD} = 50 Ω , See Figure 2	-7.2	-9.5		dB
I _{LOSS(CM)}	Common-mode insertion loss	f =1.25 GHz, R_{LOAD} = 50 Ω , See Figure 3		-2		dB
O _{IFF}	Differential OFF isolation	f =1.25 GHz, R_{LOAD} = 50 Ω , See Figure 4	-33	-38		dB
X _{TALK}	Differential crosstalk	f =1.25 GHz, R_{LOAD} = 50 Ω , See Figure 5	-33	-39		dB



OPERATING CHARACTERISTICS



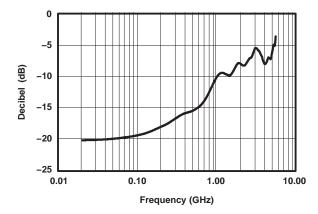


Figure 1. Differential Insertion Loss vs Frequency

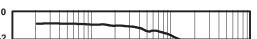
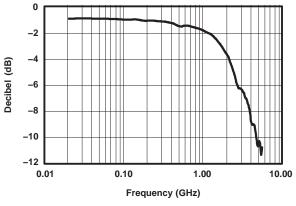


Figure 2. Differential Return Loss vs Frequency



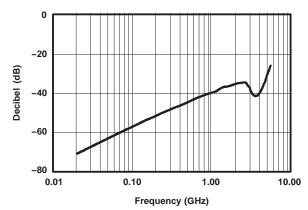


Figure 3. Common-Mode Insertion Loss vs Frequency

Figure 4. Differential OFF Isolation vs Frequency

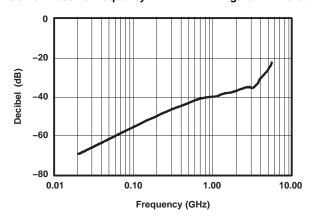
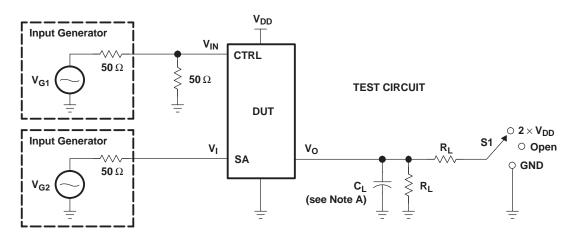


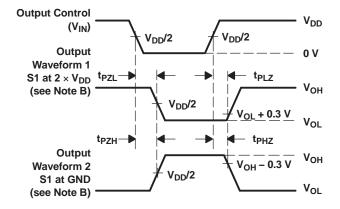
Figure 5. Differential Crosstalk vs Frequency



PARAMETER MEASUREMENT INFORMATION (Enable and Disable Times)



TEST	V _{CC}	S1	R_{L}	VI	CL	${f V}_{\Delta}$
t_{PLZ}/t_{PZL}	1.8 V ± 0.1 V	$2 \times V_{DD}$	100 Ω	GND	No Load	0.3 V
t _{PHZ} /t _{PZH}	1.8 V ± 0.1 V	GND	100 Ω	V_{DD}	No Load	0.3 V



VOLTAGE WAVEFORMS ENABLE AND DISABLE TIMES

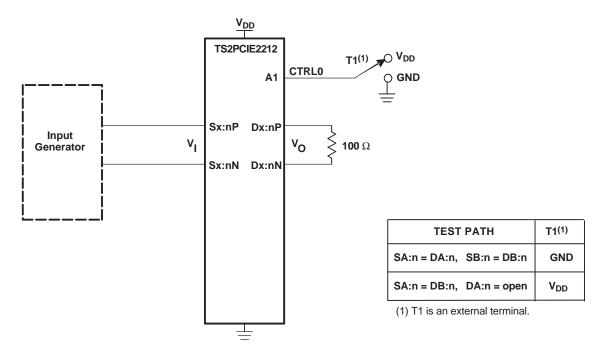
NOTES: A. C_L includes probe and jig capacitance.

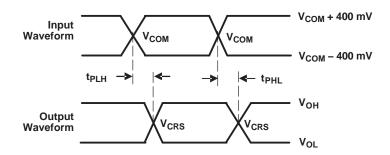
- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , $t_f \leq$ 2.5 ns. $t_f \leq$ 2.5 ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en}.

Figure 6. Test Circuit and Voltage Waveforms



PARAMETER MEASUREMENT INFORMATION





 $V_{COM} = 1.5 V$

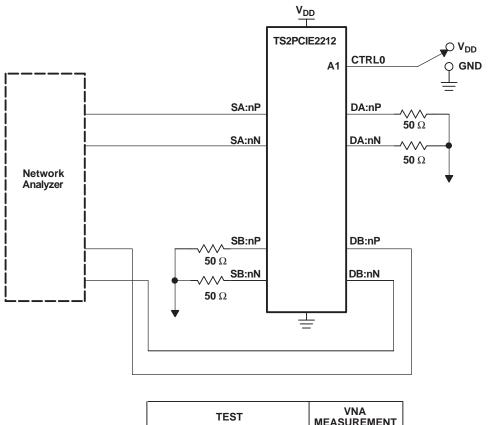
 $\ensuremath{\text{V}_{\text{CRS}}}\xspace$ is the cross point of the differential signal.

 $t_{sk} = |t_{PLHn} - t_{PHLn}|$

Figure 7. Test Circuit for Propagation Delay and Intra-Pair Skew



PARAMETER MEASUREMENT INFORMATION (continued)

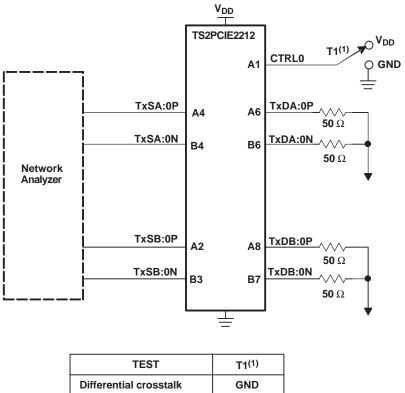


TEST	VNA MEASUREMENT
Differential insertion loss	S ₂₁
Differential return loss	S ₁₁
Common-mode insertion loss	S ₂₁

Figure 8. Differential Insertion Loss, Differential Return Loss, and Common-Mode Insertion Loss Test Circuit



PARAMETER MEASUREMENT INFORMATION (continued)



TEST	T1 ⁽¹⁾
Differential crosstalk	GND
Differential OFF isolation	V _{DD}

(1) T1 is an external terminal.

Figure 9. Differential Crosstalk and OFF Isolation Test Circuit



PACKAGE OPTION ADDENDUM

10-Dec-2020

PACKAGING INFORMATION

www.ti.com

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
TS2PCIE2212ZAHR	ACTIVE	NFBGA	ZAH	48	3000	RoHS & Non-Green	SNAGCU	Level-3-260C-168 HR	0 to 85	SE212	Samples
TS2PCIE2212ZAHRG1	ACTIVE	NFBGA	ZAH	48	3000	RoHS & Green	SNAGCU	Level-3-260C-168 HR		SE212	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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10-Dec-2020

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TS2PCIE2212ZAHRG1	NFBGA	ZAH	48	3000	330.0	12.4	5.3	5.3	1.5	8.0	12.0	Q1

PACKAGE MATERIALS INFORMATION

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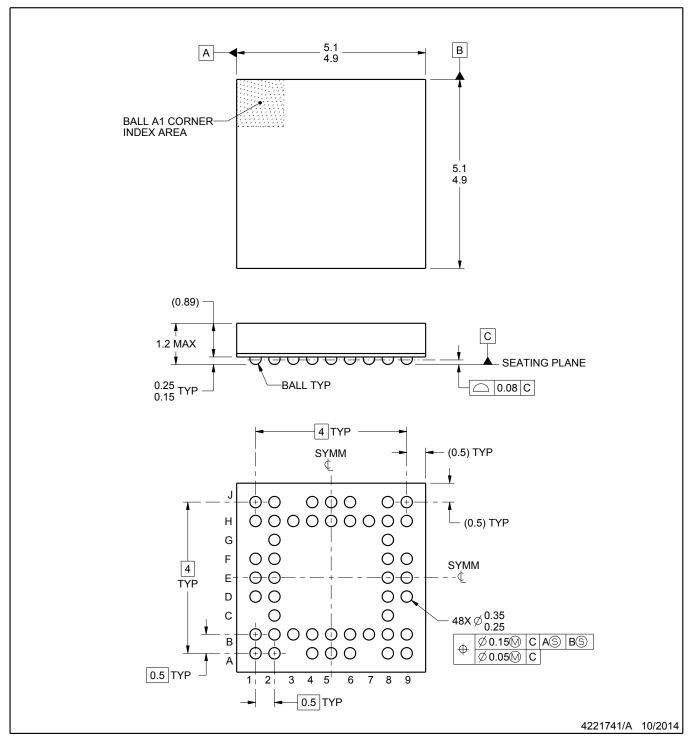


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
TS2PCIE2212ZAHRG1	NFBGA	ZAH	48	3000	336.6	336.6	31.8	



PLASTIC BALL GRID ARRAY

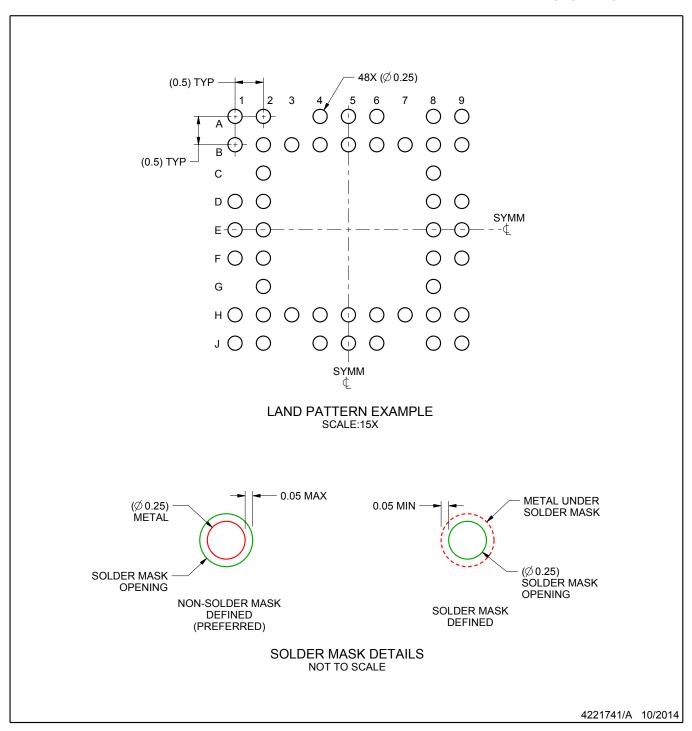


NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 2. This drawing is subject to change without notice.



PLASTIC BALL GRID ARRAY

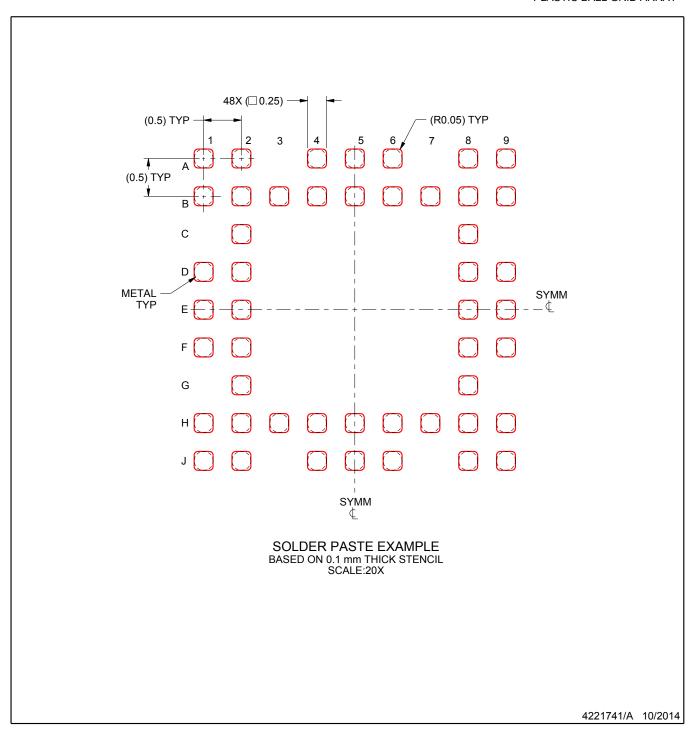


NOTES: (continued)

3. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For information, see Texas Instruments literature number SSYZ015 (www.ti.com/lit/ssyz015).



PLASTIC BALL GRID ARRAY



NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.



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